MOSFET – Power, **P-Channel, High Side Load** Switch with Level-Shift, **SC-88** 8 V, ±1.3 A

The NTJD1155L integrates a P and N-Channel MOSFET in a single package. This device is particularly suited for portable electronic equipment where low control signals, low battery voltages and high load currents are needed. The P-Channel device is specifically designed as a load switch using ON Semiconductor state-of-the-art trench technology. The N-Channel, with an external resistor (R1), functions as a level-shift to drive the P-Channel. The N-Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The NTJD1155L operates on supply lines from 1.8 to 8.0 V and can drive loads up to 1.3 A with 8.0 V applied to both VIN and VON/OFF.

Features

- Extremely Low R_{DS(on)} P-Channel Load Switch MOSFET
- Level Shift MOSFET is ESD Protected
- Low Profile, Small Footprint Package
- V_{IN} Range 1.8 to 8.0 V
- ON/OFF Range 1.5 to 8.0 V
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating			Symbol	Value	Unit	
Input Voltage (V _{DSS} , P-Ch)			V _{IN}	8.0	V	
ON/OFF Voltage (V _{GS} , N-Ch)			V _{ON/OFF}	8.0	V	
Continuous Load Current	Steady	$T_A = 25^{\circ}C$	١L	±1.3	A	
(Note 1)	State	$T_A = 85^{\circ}C$		±0.9		
Power Dissipation	Steady	$T_A = 25^{\circ}C$	PD	0.40	W	
(Note 1)	State T _A =			0.20		
Pulsed Load Current	t _p = 10 μs		I _{LM}	±3.9	А	
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to 150	°C	
Source Current (Body Diode)			۱ _S	-0.4	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	320	°C/W
Junction-to-Foot - Steady State (Note 1)	$R_{\theta JF}$	220	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

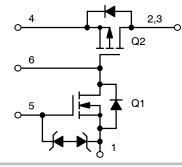


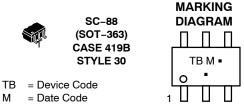
ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
	130 mΩ @ –4.5 V	
8.0 V	170 mΩ @ –2.5 V	±1.3 A
	260 mΩ @ –1.8 V	

SIMPLIFIED SCHEMATIC







Μ

(Note: Microdot may be in either location)

PIN ASSIGNMENT

D1/G2 G1 S2 2 3 D2 D2 S1

ORDERING INFORMATION

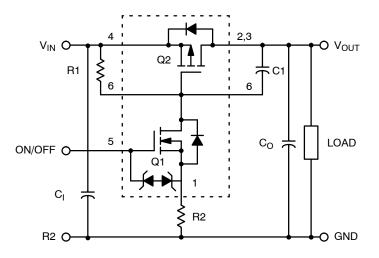
Device	Package	Shipping [†]
NTJD1155LT1G, NTJD1155LT2G	SC-88 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. Surface-mounted on FR4 board using 1 inch sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

ELECTRICAL CHARACTERISTICS (T_J = $25^{\circ}C$ unless otherwise noted)

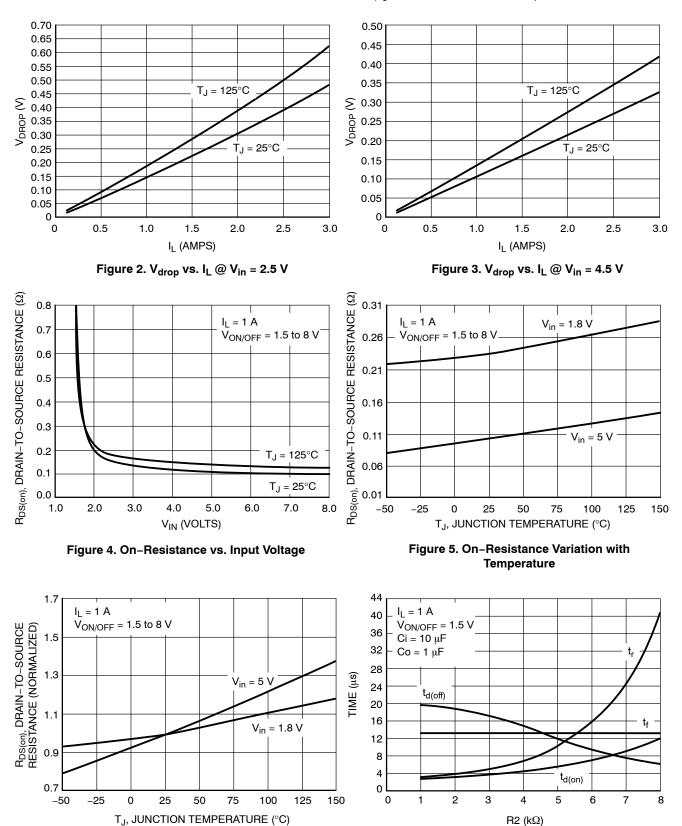
Characteristic	Symbol	Test Cond	Test Condition		Тур	Max	Unit
OFF CHARACTERISTICS		-					
Q2 Drain-to-Source Breakdown Voltage	V _{IN}	V_{GS2} = 0 V, I_{D2}	= 250 μA	-8.0			V
Forward Leakage Current	I _{FL}	V _{GS1} = 0 V,	$T_J = 25^{\circ}C$			1.0	μA
		$V_{DS2} = -8.0$ V	T _J = 125°C			10	
Q1 Gate-to-Source Leakage Current	I _{GSS}	V _{DS1} = 0 V, V _{GS}	₁ = ±8.0 V			±100	nA
Q1 Diode Forward On-Voltage	V _{SD}	I _S = -0.4 A, V _{GS1} = 0 V			-0.8	-1.1	V
ON CHARACTERISTICS							
ON/OFF Voltage	V _{ON/OFF}			1.5		8.0	V
Q1 Gate Threshold Voltage	V _{GS1(th)}	$V_{GS1} = V_{DS1}, I_D = 250 \ \mu A$		0.4		1.0	V
Input Voltage	V _{IN}	V _{GS1} = V _{DS1} , I _D = 250 μA		1.8		8.0	V
Q2 Drain-to-Source On Resistance	R _{DS(on)}	V _{ON/OFF} = 1.5 V	V _{IN} = 4.5 V I _L = 1.2 A		130	175	mΩ
			V _{IN} = 2.5 V I _L = 1.0 A		170	220	
			V _{IN} = 1.8 V I _L = 0.7 A		260	320	
Load Current	۱ _L	$I_{L} \qquad \frac{V_{DROP} \le 0.2 \text{ V}, \text{ V}_{IN} = 5.0 \text{ V},}{V_{ON/OFF} = 1.5 \text{ V}}$ $\frac{V_{DROP} \le 0.3 \text{ V}, \text{ V}_{IN} = 2.5 \text{ V},}{V_{ON/OFF} = 1.5 \text{ V}}$		1.0			A
				1.0			





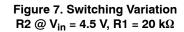
Components	Description	Values
R1	Pullup Resistor	Typical 10 k Ω to 1.0 M Ω^*
R2	Optional Slew-Rate Control	Typical 0 to 100 kΩ*
C _O , C _I	Output Capacitance	Usually < 1.0 μF
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF

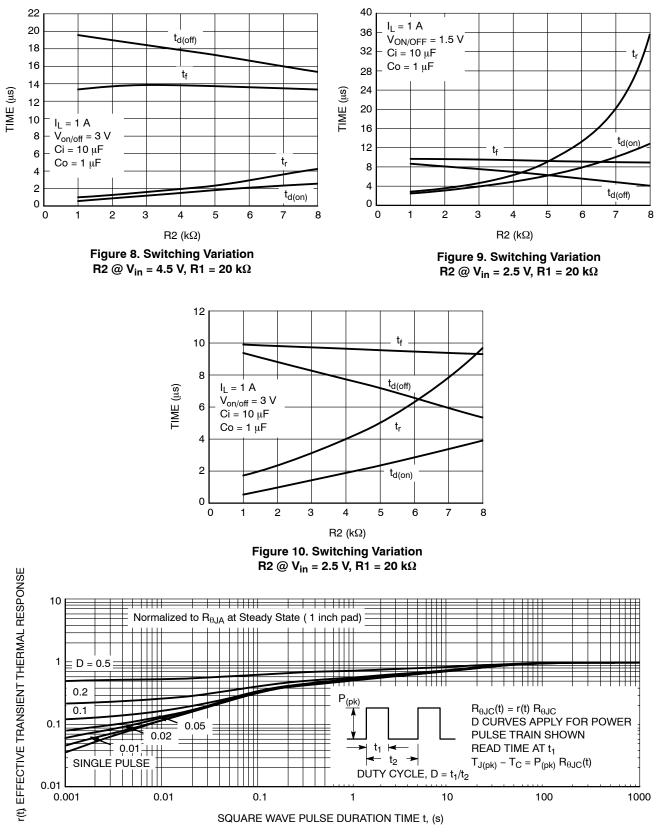
*Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.



TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)





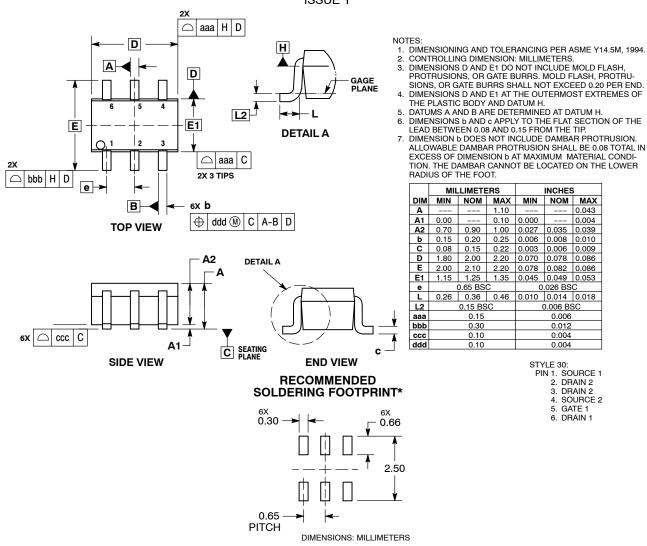


TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)



PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y**



STYLE 30: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. 5. SOURCE 2 GATE 1 6. DRAIN 1

INCHES

MIN NOM MAX

0.003 0.006 0.009

0.045 0.049 0.053

0.026 BS0

0.010 0.014 0.018

0.006 BSC

0.006

0.012

0.004

0.004

1.00 0.027 0.035 0.039 0.20 0.25 0.006 0.008 0.010

2.20 0.078 0.082 0.086

0.043

0.004

1.10

0.22

1.25 1.35

0.90

0.15

0.65 BS0

0.15 BSC

0.15

0.30

0.10

0.10

0.10 0.000

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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